

EE140/240A Analog Integrated Circuits

↳ more HW, project. req.
waitlist, convert enrdad

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HW - self grade + 3rd check. 1st are today!

Lab 5 - 5 weeks bipolar on breadboard

Project then cadence

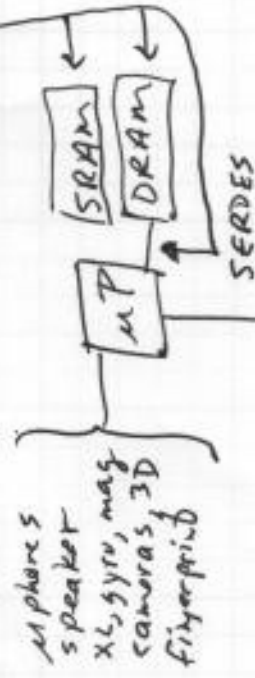
2 midterms (9/27 and 11/01 WK 5, 10)?

Final - comprehensive

What is analog? Anything not digital?

(Quantized/discrete values in time & I/V)

and many things that are digital



power/battery mgmt
power-on, reset

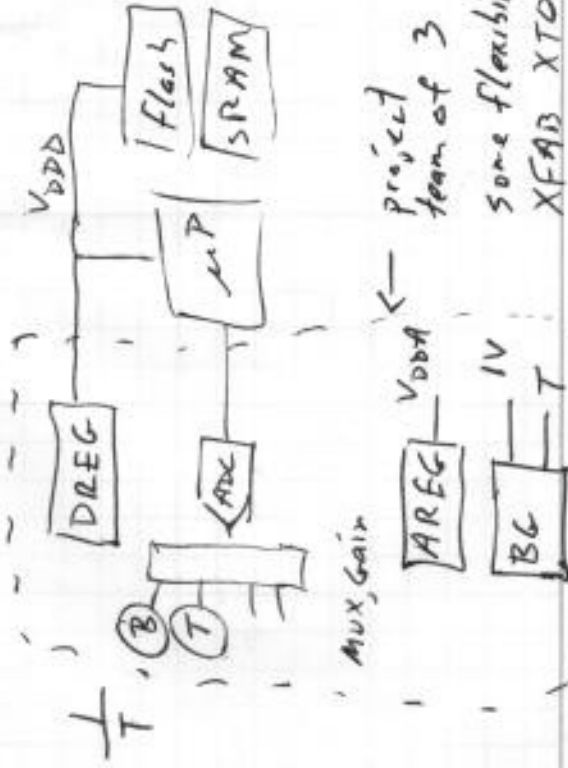
network: optical, ethernet, wifi

Books: Razavi, CHLM
U.G. Grad.

Who ami? SD, B, LA, B, Dust → Linear → Analog, B

Research: in robots
smart dust → low power circuits

typical embedded microcontroller



Project team of 3
some flexibility
XFAB XTOIB

How do you build these?

Mostly op-amps, all w/ different specs

gain, BW

input/output swing, impedance

power constraint (area constraint)

operating over process V_t , n , n_{ox} , ...

Variation in Voltage V_{BAT} : 3.2-1.6

temperature -40...+85C

tools: pencil & paper

breadboard }
oscilloscope }

verify your design
give clues to things
that we missed

SPICE faster than breadboarding

You don't design w/ SPICE

cadence - industrial grade
schematic

layout + extraction / time

Use a small number of topologies
diff pair
cascode
Feedback

common emitter

current mirror

Design: pick topologies

choose currcnts, w/L to meet specs



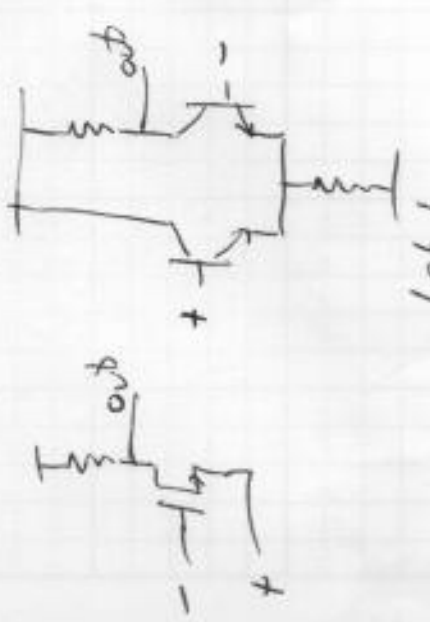
ideal

gain
BW
 R_{in}
 R_{out}
 V_{cm}
power
input offset
CMRR
stability

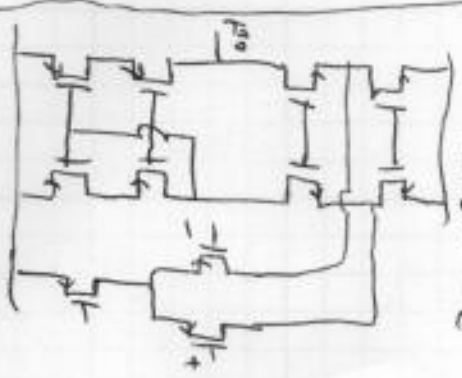
∞
 ∞
 ∞
0
 $-\infty$ to ∞
0
0
 ∞
uncond.

real
 10^{-10}^6
 $10^3 - 10^{11}$ Hz
 $< 1 \Omega \dots > 10^9 \Omega$
0.1%... > supply
 $10^{-9} - 1$ W
 $\mu V - 100$ mV
0... 120 dB
as needed

Exampler



(IC prodim)
Lab 1
(IC prodim)



Rozavi 9.15
GMLN 6.2.9

Analogy industry - internal consumers

cell phone companies Apple, Samsung

Qualcomm, Huawei

DoD

HP vendors

Intel, AMD, ...

communication systems Cisco, Marvell,

there are a lot of jobs

Analogy IC industry - Semiconductor Companies

2017 Analogy IC revenue, \$B

| | |
|-----------|----|
| TI | 10 |
| ADI | 4 |
| skyworks | 4 |
| Infineon | 3 |
| ST | 3 |
| NXP | 2 |
| Maxim | 2 |
| ON Semi | 2 |
| Microchip | 1 |
| Renesas | 1 |

\$55B

from qmysilicon.com

what should you remember from 10.5?

Device Physics - "large signal" model

non-linear

regions of operation linearization

off, triode, saturation

g_m, r_o

frequency response

Hauschild, Bode

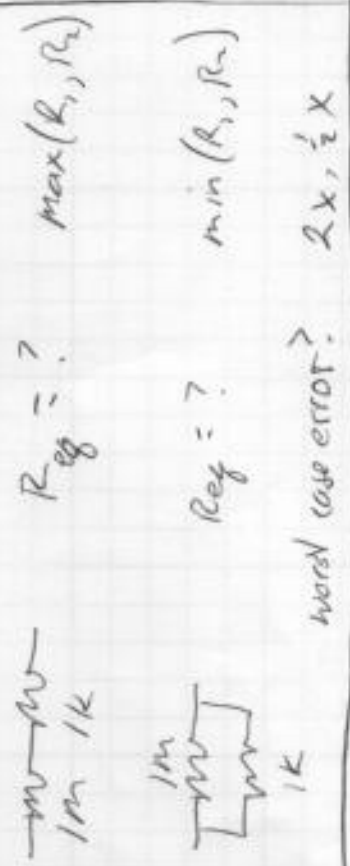
simple amplifier

CS/CE

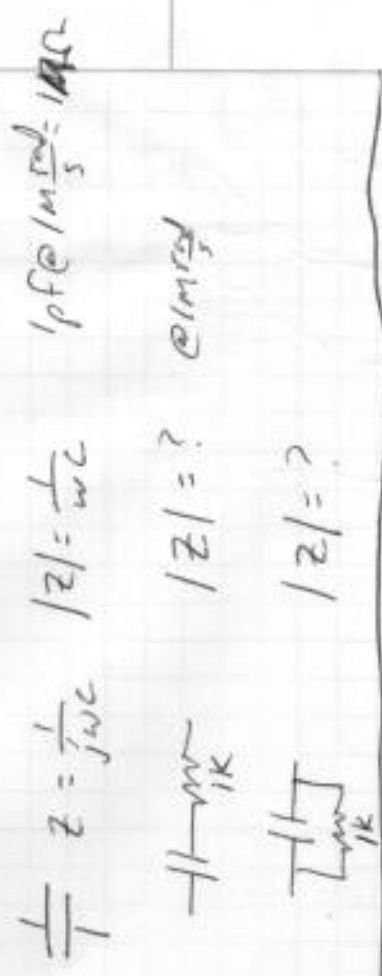
CG/CB

CD/CC

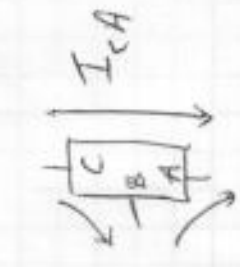
Analogue designers rarely worry about the 2nd digit of any answer
 Simplify, solve by inspection
 intuition, pattern matching, rules of thumb, ...



LC and C are just frequency dependent resistors
 (yes, they have phase)
 Yes, we will take it into account
 but for intuition...



3 terminal devices



- 1) I_{CA} depends mostly on V_{BA} strongly
- 2) I_{CA} depends weakly on V_{CA}
- 3) I_{DA}, I_{CB} are $\ll I_{CA}$

(tube (1911), MOSFET (1927), BJT, (1947), JFET (1950))
~~the~~ *FET, relays, nano*, ...

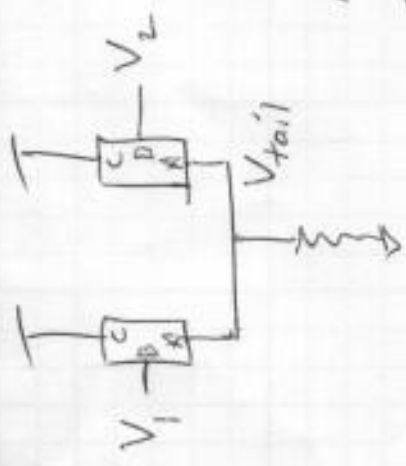
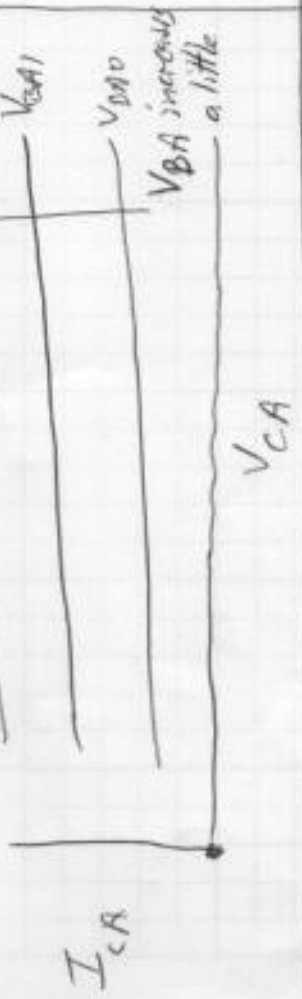
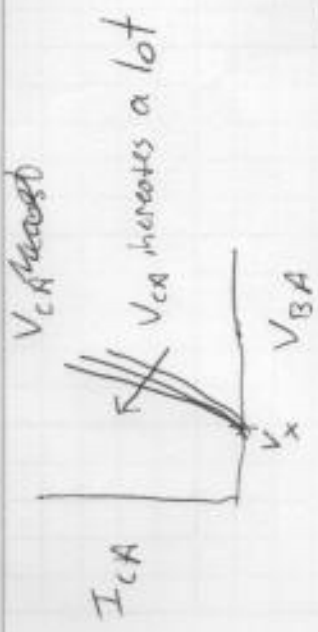
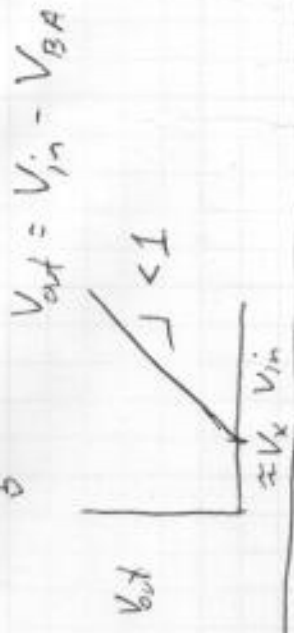
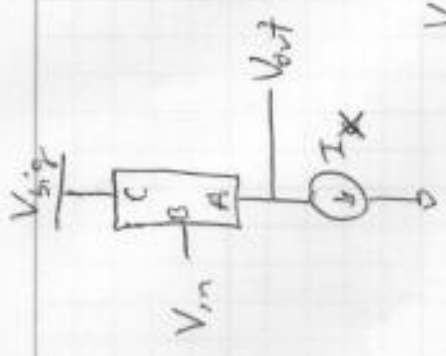
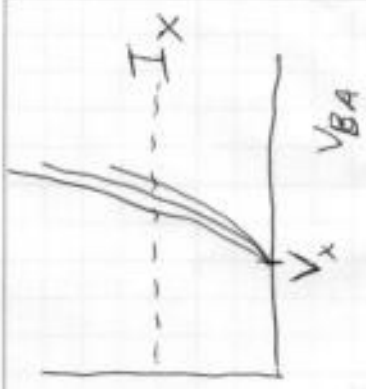
all share these properties

we still use circuit topologies developed 70-100 years ago



exponential BJT, subV MOS
 quadratic long MOS
 linear short MOS
 $V_{DA}^{3/2}$
 tube

threshold voltage
 diode "turn on" voltage
 never "sharp"



$V_{tail} \approx \max(V_1, V_2) - V_x$
 if $|V_1 - V_2|$ is "big" then one device will be off.

$V_x = 1V$

| | | |
|-----------|---|---|
| $V_1 = 5$ | 7 | 5 |
| $V_2 = 5$ | 5 | 5 |